

## Supporting Information

### Microstructures, Grain and Nanowires Growth during Selective Laser Melting of Ag-Cu/Diamond Composites

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### Content

**Figure S1:** The morphology of diamond particles.

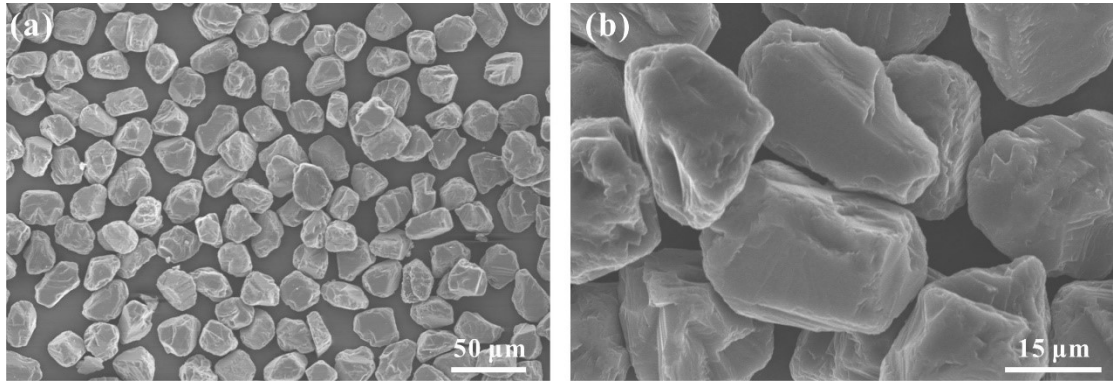
**Table S1:** The detailed parameters of rectangular contour samples.

**Eq S1:** The line energy density (LED, J/m)

**Figure S2:** LED at different processing parameters of rectangle contours.

**Table S2:** The processing parameters used to manufacture cubic samples.

**Figure S3:** Thermophysical properties of Ag-Cu powders.



**Figure S1.** The morphology of diamond particles.

**Table S1:** The detailed parameters of rectangular contour samples.

Process parameters	Rectangular contour samples
Laser power (W)	40, 50, 60, 70, 80, 90, 100, 110, 120
Scanning speed (mm/s)	400, 600, 800, 1000, 1200, 1400, 1600, 1800, 2000
Layer thickness ( $\mu\text{m}$ )	100
Speciment geometry ( $\text{mm}^2$ )	$1 \times 5$

The line energy density (LED, J/m) is defined as **Eq S1**:

$$LED = \frac{P}{v} \quad (1)$$

where  $P$  represents the laser power (W) and  $v$  is the scanning speed (mm/s), respectively.

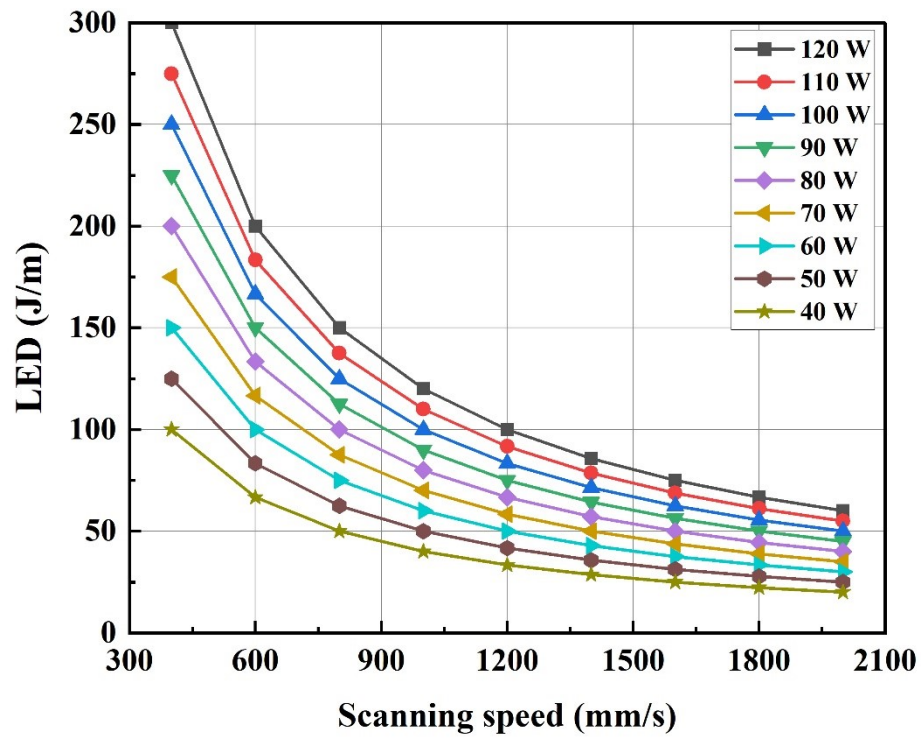
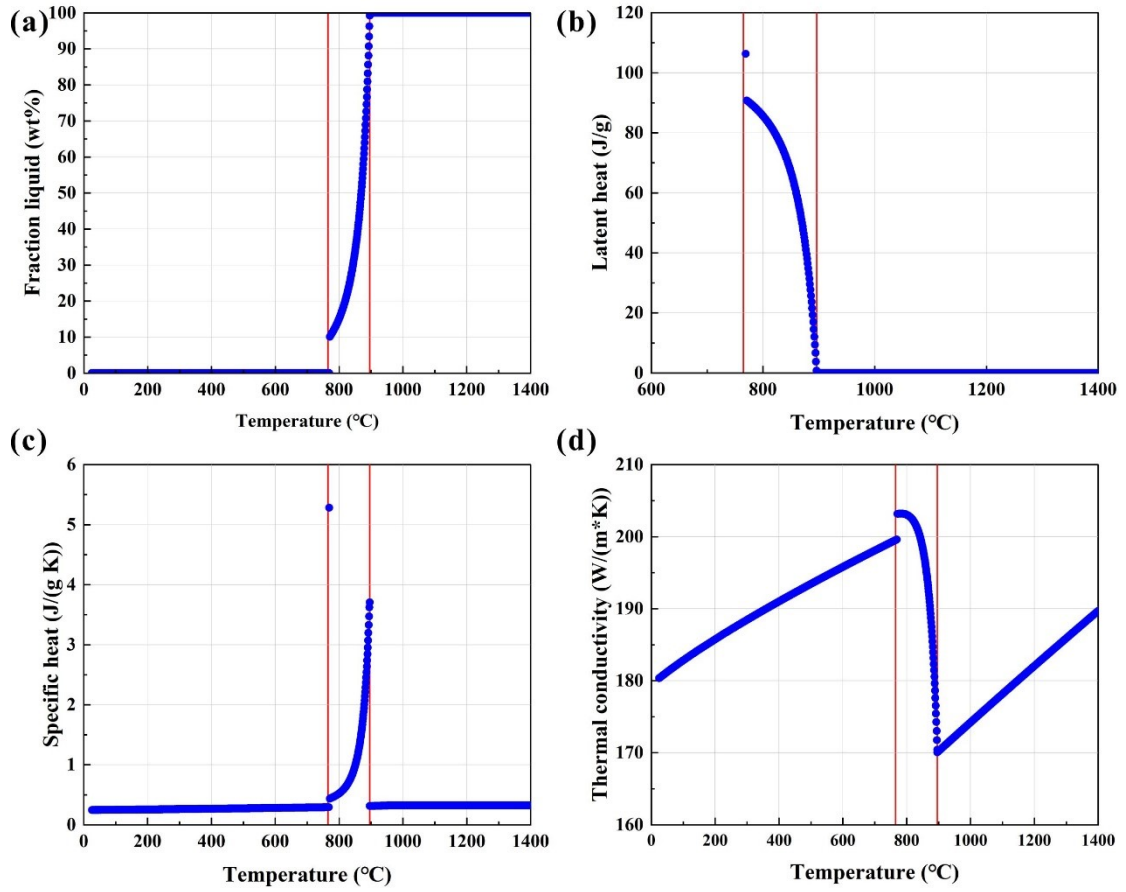


Figure S2: LED at different processing parameters of rectangle contours.

**Table S2:** The processing parameters used to manufacture cubic samples.

Types	Input volume energy density (J/mm <sup>3</sup> )	Processing parameter $P$ (W), $v$ (mm/s), $h$ (mm), $t$ (mm)
Over melting	562.5	$P = 90, v = 800, h = 0.01, t = 0.02$
	625	$P = 100, v = 800, h = 0.01, t = 0.02$
	500	$P = 100, v = 1000, h = 0.01, t = 0.02$
	600	$P = 120, v = 1000, h = 0.01, t = 0.02$
	300	$P = 60, v = 1000, h = 0.01, t = 0.02$
Good melting	450	$P = 90, v = 1000, h = 0.01, t = 0.02$
	357.1	$P = 100, v = 1400, h = 0.01, t = 0.02$
	428.6	$P = 120, v = 1400, h = 0.01, t = 0.02$
Weak melting	200	$P = 40, v = 1000, h = 0.01, t = 0.02$
	166.7	$P = 40, v = 1200, h = 0.01, t = 0.02$
	250	$P = 60, v = 1200, h = 0.01, t = 0.02$
	214.3	$P = 60, v = 1400, h = 0.01, t = 0.02$



**Figure S3:** Thermophysical properties of Ag-Cu powders. (a) solidification curve; (b) latent heat curve; (c) specific heat curve; and (d) thermal conductivity curve.